DATASHEET

4 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER AC INPUT PHOTOCOUPLER EL814 Series



Features

- AC input response
- Current transfer ratio (CTR: Min. 20% at I_F = ±1mA, V_{CE} = 5V)
- High isolation voltage between input
- and output (Viso = 5000 V rms)
- Wide Operating temperature range -55~110°C
- High collector-emitter voltage $V_{CEO} = 80V$
- Compact dual-in-line package
- The product itself will remain within RoHS compliant version
- Compliance with EU REACH
- UL and cUL approved (No. E214129)
- VDE approved (No. 132249)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved
- · CQC approved

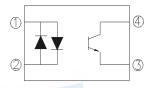
Description

The EL814 series of devices each consist of two infrared emitting diodes, connected in inverse parallel, optically coupled to a phototransistor detector. They are packaged in a 4-pin DIP package and available in side-lead spacing and SMD option.

Applications

- AC line monitor
- Programmable controllers
- Telephone line interface
- Unknown polarity DC sensor

Schematic



- Pin Configuration
- 1. Anode / Cathode
- 2. Cathode / Anode
- 3. Emitter
- 4. Collector

Absolute Maximum Ratings (Ta=25℃)

	Parameter	Symbol	Rating	Unit
	Forward current	١ _F	±60	mA
loout	Peak forward current (t = 10µs)	I _{FM}	1	А
Input	Power dissipation	D	100	mW
	Derating factor (above 100 °C)	P _D —	2.9	mW/⁰C
	Power dissipation	D	150	mW
	Derating factor (above 100 °C)	P _C —	5.8	mW/ºC
Output	Collector-Emitter voltage	V _{CEO}	80	V
	Emitter-Collector voltage	V _{ECO}	6	V
Total Powe	er Dissipation	P _{TOT}	200	mW
Isolation V	'oltage*1	V _{ISO}	5000	V rms
Operating Temperature		T _{OPR}	-55 to 110	°C
Storage Temperature		T _{STG}	-55 to 125	°C
Soldering	Temperature* ²	T _{SOL}	260	°C

Notes

*1 AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1, 2 are shorted together, and pins 3, 4 are shorted together. *2 For 10 seconds

Electro-Optical Characteristics (Ta=25°C unless specified otherwise)

nput						
Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Forward Voltage	V _F	-	1.2	1.4	V	$I_F = \pm 20 \text{mA}$
Input capacitance	C _{in}	-	50	250	pF	V = 0, f = 1KHz
Dutput						
Parameter	Symbol	Min	Тур.	Max.	Unit	Condition
Collector-Emitter dark current	I _{CEO}	-	-	100	nA	$V_{CE} = 20V, I_F = 0mA$
Collector-Emitter breakdown voltage	BV_{CEO}	80	-	-	V	$I_{\rm C} = 0.1 {\rm mA}$
Emitter-Collector breakdown voltage	BV_{ECO}	6	-	-	V	I _E = 0.1mA
ransfer Characterist	tics					
ransfer Characterist Parameter	t ics Symbol	Min	Тур.	Max.	Unit	Condition
Parameter Current EL814	Symbol	Min 20	Тур. -	Max. 300	5	
Parameter			Тур. -		Unit %	Condition $I_F = \pm 1 \text{mA}$, $V_{CE} = 5 \text{V}$
Parameter Current EL814 Transfer	Symbol	20		300	5	
Parameter Current Transfer ratio	Symbol	20 50		300 150	5	$I_F = \pm 1 \text{mA}$, $V_{CE} = 5 \text{V}$
Parameter Current Transfer ratio CTR Symmetry Collector-emitter	Symbol	20 50		300 150 1.3	%	$I_F = \pm 1 \text{mA}$, $V_{CE} = 5 \text{V}$ $I_F = \pm 1 \text{mA}$, $V_{CE} = 5 \text{V}$
Parameter Current Transfer ratio EL814 EL814A CTR Symmetry Collector-emitter saturation voltage	Symbol CTR V _{CE(sat)}	20 50 0.7	0.05	300 150 1.3 0.2	% V	$I_F = \pm 1 \text{mA}, V_{CE} = 5V$ $I_F = \pm 1 \text{mA}, V_{CE} = 5V$ $I_F = \pm 20 \text{mA}, I_c = 1 \text{mA}$
Parameter Current Transfer ratio EL814 EL814 EL814A CTR Symmetry Collector-emitter saturation voltage Isolation resistance	Symbol CTR V _{CE(sat)} R _{IO}	20 50 0.7	0.05	300 150 1.3 0.2	% V Ω	$I_{F} = \pm 1 \text{mA}, V_{CE} = 5V$ $I_{F} = \pm 1 \text{mA}, V_{CE} = 5V$ $I_{F} = \pm 20 \text{mA}, I_{C} = 1 \text{mA}$ $V_{IO} = 500 \text{Vdc}, 40 \sim 60\% \text{R.H}$ $V_{CE} = 5V, I_{C} = 2 \text{ mA}, R_{L} = 100\Omega$
Parameter Current Transfer ratio EL814 EL814A CTR Symmetry Collector-emitter saturation voltage Isolation resistance Cut-off frequency	Symbol CTR V _{CE(sat)} R _{IO} f _c	20 50 0.7	0.05 10 ¹¹ 80	300 150 1.3 0.2 - -	% V Ω kHz	$I_{F} = \pm 1 \text{mA}, V_{CE} = 5V$ $I_{F} = \pm 1 \text{mA}, V_{CE} = 5V$ $I_{F} = \pm 20 \text{mA}, I_{c} = 1 \text{mA}$ $V_{IO} = 500V \text{dc}, 40 \sim 60\% \text{R.H}$ $V_{CE} = 5V, I_{C} = 2 \text{ mA}, R_{L} = 100\Omega$ -3dB

* Typical values at $T_a = 25^{\circ}C$

Figure 2. Normalized Current Transfer Ratio vs Forward Current

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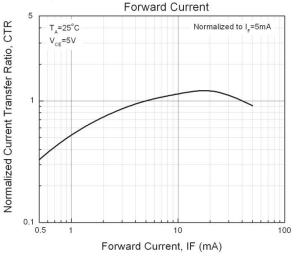


Figure 4. Dark Current vs Ambient Temperature

Typical Electro-Optical Characteristics Curves

Figure 1. Forward Current vs Forward Voltage

-55°C

1.4

1.6

1.8

10000

1000

100

10

0.1

0.01

1E-3↓ -60

Collector Current, I_c (mA)

-40

-20

0 20

V_{CE}= 10 V

25°C

110°C

1.0

1.2

100

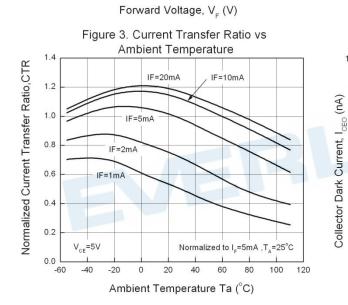
10

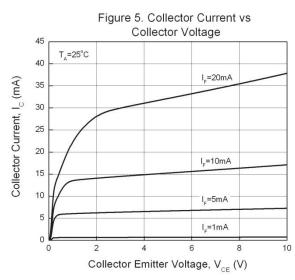
0.1

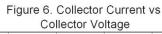
0.6

0.8

Forward Current, I_F(mA)







Ambient Temperature, Ta (°C)

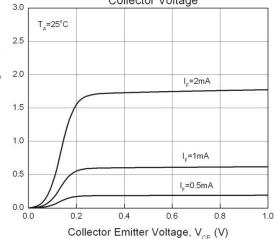
40

60

80

100

120



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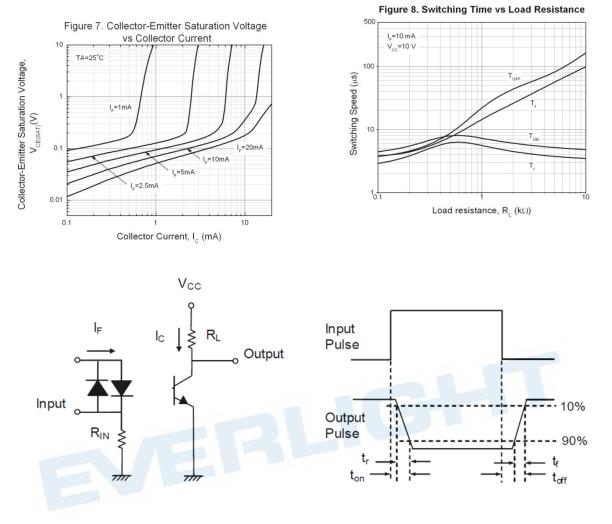
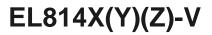


Figure 9. Switching Time Test Circuit & Waveforms

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Order Information

Part Number



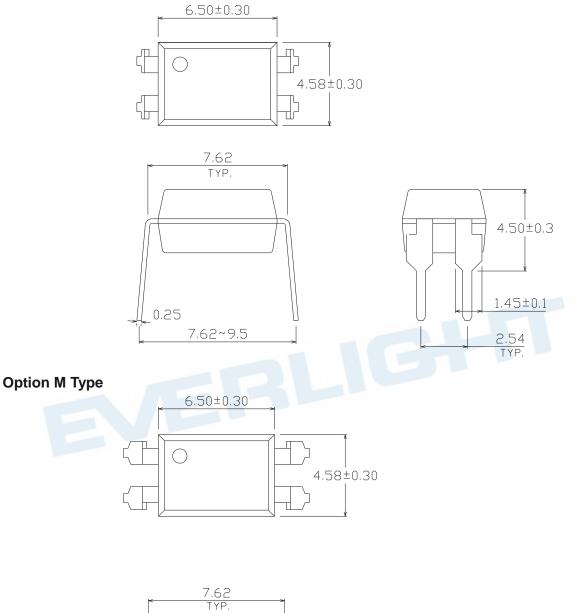
Notes

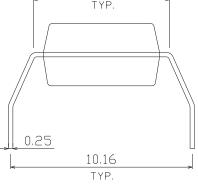
- X = Lead form option (S, S1, M or none)
- Y = CTR Rank (A or none)
- Z = Tape and reel option (TA, TB, TU, TD or none)
- V = VDE safety (optional)

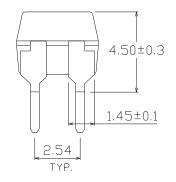
Option	Description	Packing quantity
None	Standard DIP-4	100 units per tube
М	Wide lead bend (0.4 inch spacing)	100 units per tube
S (TA)	Surface mount lead form + TA tape & reel option	1000 units per reel
S (TB)	Surface mount lead form + TB tape & reel option	1000 units per reel
S1 (TA)	Surface mount lead form (low profile) + TA tape & reel option	1000 units per reel
S1 (TB)	Surface mount lead form (low profile) + TB tape & reel option	1000 units per reel
S (TU)	Surface mount lead form + TU tape & reel option	1500 units per reel
S (TD)	Surface mount lead form + TD tape & reel option	1500 units per reel
S1 (TU)	Surface mount lead form (low profile) + TU tape & reel option	1500 units per reel
S1 (TD)	Surface mount lead form (low profile) + TD tape & reel option	1500 units per reel

Package Dimension (Dimensions in mm)

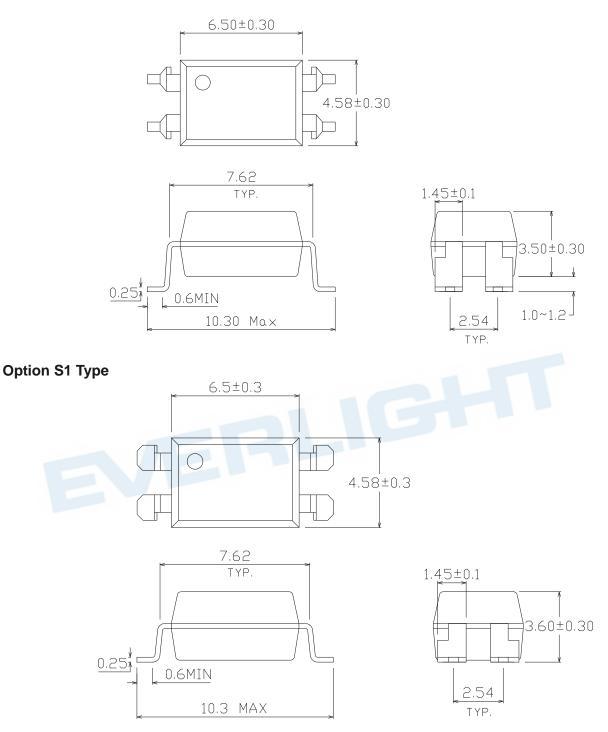
Standard DIP Type





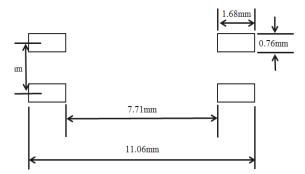


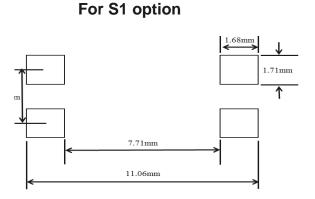
Option S Type



Recommended pad layout for surface mount leadform

For S option





Notes

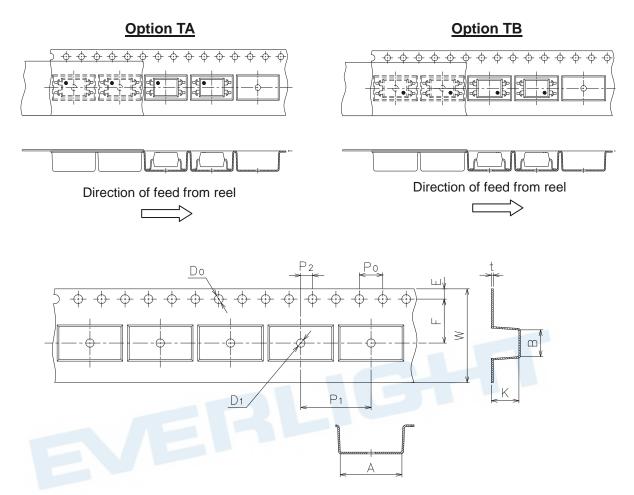
Suggested pad dimension is just for reference only. Please modify the pad dimension based on individual need.

Device Marking

Notes

EL	denotes EVERLIGHT
814	denotes Device Number
F	denotes Factory Code (G: China and Green part)
R	denotes CTR Rank (A or none)
Y	denotes 1 digit Year code
WW	denotes 2 digit Week code
V	denotes VDE (optional)

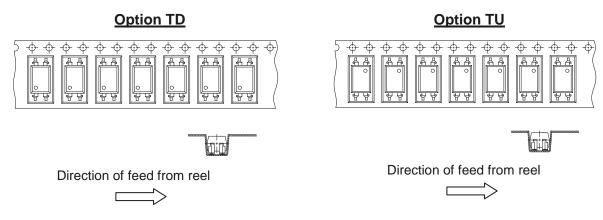
Tape & Reel Packing Specifications



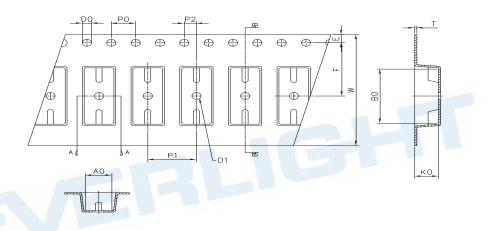
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Dimension No.	Α	В	Do	D1	Е	F
Dimension (mm) S	10.5±0.1	4.65±0.1	1.5±0.1	1.50±0.1	1.75±0.1	7.5±0.1
Dimension (mm) S1	10.5±0.1	4.65±0.1	1.5±0.1	1.50±0.1	1.75±0.1	7.5±0.1
Dimension No.	Ро	P1	P2	t	W	К
Dimension No. Dimension (mm) S	Po 4.0±0.1	P1 12.0±0.1	P2 2.0±0.1	t 0.4±0.1	W 16.0±0.3	К 5.05±0.1





Tape dimensions



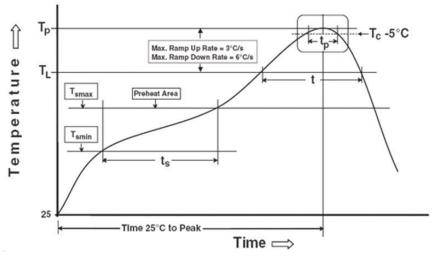
Dimension No.	Ao	Во	Do	D1	Е	F
Dimension (mm) S.S1	4.90±0.1	10.40±0.1	1.5±0.1	1.50±0.1	1.75±0.1	7.50±0.1
Dimension No.	Ро	P1	P2	t	W	Ко



Precautions for Use

1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Notes

Preheat

i ionoat	
Temperature min (T _{smin})	150 °C
Temperature max (T _{smax})	200°C
Time (T _{smin} to T _{smax}) (t _s)	60-120 seconds
Average ramp-up rate (T_{smax} to T_p)	3 °C/second max
Other	
Liquidus Temperature (T_L)	217 °C
\mathbf{T}	00.400

Time above Liquidus Temperature (t $_{L}$) Peak Temperature (T $_{P}$) Time within 5 °C of Actual Peak Temperature: T $_{P}$ - 5°C Ramp- Down Rate from Peak Temperature Time 25°C to peak temperature Reflow times 217 °C 60-100 sec 260°C 30 s 6°C /second max. 8 minutes max. 3 times

Reference: IPC/JEDEC J-STD-020D

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